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PTO/SB/08A (08-03)

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		Filing Date	Not Yet Accorded
		First Named Inventor	Andrew G. Norman
		Art Unit	Not Yet Accorded
		Examiner Name	Not Yet Accorded
Sheet	1	of	2
		Attorney Docket Number	NREL IR 01-09

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NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No.'	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			T ²
/RK/	1	Norman, A.G. et al., "Phase Separation and Facet Formation During the Growth of (GaAs)1-2(Ge2)x Alloy Layers by Metal Organic Vapor Phase Epitaxy," Inst. Phys. Conf. Ser. No. 164, 171 (1999), pgs. 171-174.			
/RK/	2	Norman, A.G. et al., "Ge-related Faceting and Separation During the Growth of Metastable (GaAs)1-2 (Ge2)x Alloy Layers by Metal--Organic Vapor Phase Epitaxy," Appl. Phys. Lett. 74, 1382 (1999)			
/RK/	3	Zakharov, N.D. et al., "Structure and Optical Properties of Si/InAs/Si Layers Grown by Molecular Beam Epitaxy on Si Substrate," Appl. Phys. Lett. Vol. 76, No. 19, pgs. 2667-2679 (2000).			
/RK/	4	Heitz, R. et al., "Optical Properties of InAs Quantum Dots in a Si Matrix," Appl. Phys. Lett. 74, 1701 (1999), Physica E7, 317 (2000)			

Examiner Signature	/Robert Kunemund/	Date Considered	03/16/2007
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